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MITSUBISHI ELECTRIC CORPORATION

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SPECIFICATION	CHECKED BY	Е			
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	DATE				

### Hybrid Integrated Circuit Amplifier for W-CDMA

- 1. Type No. BA01232E 01
- 2. Structure Hybrid Integrated Circuit
- 3. Function 1920~1980MHz Power Amplification
- 4. Quality Grade General grade
- 5. Outline G475584(GH-39)

#### 6. Absolute Maximum Ratings (Tc=25°C)

PARAMETER	SYMBOL	CONDITION	VALUE	UNIT
	Vc1	Po≤562mW(27.5dBm).		
Supply Voltage	Vc2	Vref=2.9V	6.0	V
Supply voltage	Vcb			
	Vref	Vc1=Vc2=3.5V,Vcb=2.9V	3.5	V
Input Power	Pin		5.01 (7)	mW (dBm)
Operation Temperature	Tc(op)		-20 ~ +85	°C
Storage Temperature	Tstg		-30 ~ +95	°C

Note : Each maximum rating is guaranteed independently. Please take care that BA01232E is operated under these conditions at the worst case on your terminal.

Mitsubishi Electric Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i)placement of substitutive, auxiliary, circuits, (ii)use of non-flammable material or (iii)prevention against any malfunction or mishap..

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7. Electrical Ch	naracteristics	(Ta	=25°C unless otherwise note	d, ZG=ZI	L=50ohm	l)	
PARAMERTER SVMPC		Note	CONDITIONS		UNIT		
	STWDOL	Note	CONDITIONS	MIN	TYP	MAX	UNII
Frequency Range	freq	-	-	1920	-	1980	MHz
Idle Current on	Icqt_on	1	Pin : OFF, Vc1=Vc2=3.5V Vcb=Vref=2.9V	-	35	55	mA
Idle Current off	Icqt_off	1	Pin : OFF, Vc1=Vc2=3.5V Vcb=2.9V, Vref=0V	-	-	10	μΑ
Output Power	Pout	-	Vc1=Vc2=3.5V, Vcb=Vref=2.9V ZG=ZL=50Ω,	562 [27.5]	-	-	mW [dBm]
Gain	Gp	-		24.5	26.5	28.5	dB
Total Current	Ict	1		-	342	374	mA
Total Efficiency	PAE	5		[42.4]	[46.3]	-	[%]
Vcb Current	Icb	-	Vc1=Vc2=3.5V, Vcb=Vret=2.9V Po=562mW[27.5dBm] (Pin : control)	-	4.0	6.0	mA
Vref Current	Iref	-	$ZG=ZL=50\Omega$ ,	-	1.0	2.0	mA
Adjacent Channel Leakage Power Ratio(±5MHz)	ACLR-5	-	ACLR : Offset ±5,10MHz Bandwidth=3.84MHz	-	-41	-38	dBc
Adjacent Channel Leakage Power Ratio(±10MHz)	ACLR-10	-			-52	-48	dBc
Input VSWR	ρin	2		-	-	3	-
2nd Harmonics	2fo	2		·	-40	-33	dBc
3rd Harmonics	3fo	2			-45	-40	dBc
Rx Band Noise Power	-	3,6	Rx:2110 – 2170MHz Vc1=Vc2=3.5V, Vcb=Vref=2.9V Po=562mW[27.5dBm] (Pin : control) ZG=ZL=50Ω, RES BW=1MHz Noise Marker, Averaging Mode	-	10.0 x10e-15 [-140]	31.6 x10e-15 [-135]	mW/Hz [dBm/Hz]
Stability	-	3	Vc1=Vc2=4.2V, Vcb=Vref=2.9V ZG= 50Ω Pin=1.26mW (1dBm) Load VSWR=3:1, All Phase	Parasitic ≤ -70dBc	oscillation	level	-
Damage with Standing	-	3,4	Vc1=Vc2=4.2V, Vcb=Vref=2.9V ZG= 50Ω, Pin=1.26mW (1dBm) Load VSWR=10:1, All Phase Time=10sec.	No dama	ge		-
		Op	erating Condition Recommendation	n			
	Vc1,Vc2,			[1.0]	3.5	4.2	V
Supply Voltage	Vcb			2.5	2.90	4.2	V
	Vref			2.85	2.90	2.95	V

Note1. Icqt=Icq1+Icq2, Ict=Ic1+Ic2

Note2. Design assurance. For confirmation, sampling test (10pcs/lot) is done in the first 10 lots.

Note3. Design assurance. For confirmation, sampling test (3pcs/lot) is done in the first 5 lots.

Note4. No modulation, unless otherwise noted W-CDMA HPSK modulation (Chip rate=3.84Mcps)

Note5. We calculate the Total Efficiency(PAE) from Input Power value, Output Power value and Total Current value.

The PAE is reference value, as we specify each parameter at each condition.

Note6. Settings of the Spectrum Analyzer: RBW=VBW=1MHz, SWP=20ms, Detector Mode=Sample, Average, Sweep Times=20times. Note7. In this table, we use the symbol [] that is the reference value.

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8. Pin Configuration and Marking



#### [Note]

Marked by laser process or ink printing.

#### [Lot number]

Symbol	Content	Description
Y	Year	This single figure shows the year when the assembly of the lot is started.
		The period of the year is from April to March.
		(e.g.) 3 The lot was assembled in Apr./2003 to Mar./2004
М	Month	This single figure shows the month when the assembly of the lot is
		started.
		Apr.=1, May=2, Nov.=8, Dec.=9, Jan.=X, Feb.=Y, Mar.=Z
SN	Serial	This combination of double alphabets(except I,O) shows the order when
	Number	the assembly of the lot is started in the month.
		AA AB AY AZ BA BB

#### 9. Pin Description

Pin No.	Pin name	Function
1	Pin	RF input
2	Vc1	Supply voltage of 1st stage HBT
3	Vc2	Supply voltage of 2nd stage HBT
4	Pout	RF output
5	Vcb	Bias circuit supply voltage of 1st and 2nd
6	Vref	Reference bias to set idle current
7	GND	

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#### 10. Block Diagram



Note: DC cut capacitors of Pin/Pout are enclosed in the module.

#### 11. Package Outline



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